GaAs MMIC Digital Attenuator Chip, DC-50GHz

Performance characteristics

Frequency range: DC-50GHz Insertion loss: 1.3dB typ

Attenuation range: 0.25~3.75dB

Bit Count: 4 digits

Attenuation accuracy (RMS): 0.15dB

Power supply voltage: -5V Control voltage: 0/+5V 50Ohm input/output

Chip size: 1.36 x 1.31 x 0.1mm

Product Introduction

GDA-0050-4B-PD is a GaAs MMIC 4-bit Digital attenuator chip, with a frequency range of DC~50GHz, insertion loss of 1.3dB, switching speed of 50ns, integrated driver inside the chip, and 0/+5V control. The chip through-hole metallization process ensures good grounding, and the back is metallized, suitable for eutectic sintering or conductive adhesive bonding processes.

Usage restriction parameter ¹			
Power supply voltage range	-6V		
Control voltage range	-0.5V~+5.5V		
Maximum input power	+27dBm		
working temperature	-55 ~ +85°C		
Storage temperature	-65 ~ +150°C		

[1] Exceeding any of the above maximum limits may result in permanent damage.

Electrical parameters(Ta=+25° C, VEE=-5V, VC=0/+5V Control)				
Index	Minimum value	Typical value	Maximum value	Unit
frequency range	DC~50			GHz
insertion loss	-	1.3	-	dB
Attenuation range	0.25~3.75 dB			dB
Attenuation step	0.25 dB			dB
Attenuation number	4 bit			bite
Attenuation accuracy (all frequency bands)	-	-	-0.6 ~ +0.3	dB
Attenuation accuracy RMS	-	0.15	-	dB
Additional phase shift	-	-	-3.2 ~ +1.9	degree
input return loss	-	23	-	dB
Output Return Loss	-	20	-	dB

Add: 101 cecil street #14-10, tong eng building singapore 069533 Email: info@standardcircuit.com

Web: www.standardcircuit.com Tel: +65 82613258



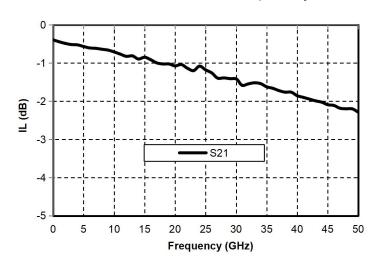
GDA-0050-4B-PD

Switching speed	-	50	-	ns
P-1dB	-	22	-	dBm
current		10		mA

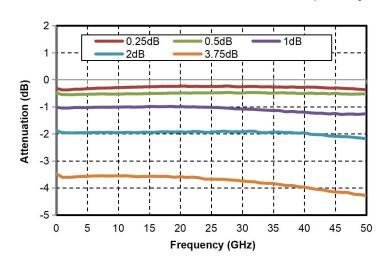
GaAs MMIC Digital Attenuator Chip, DC-50GHz

Main indicator testing curve

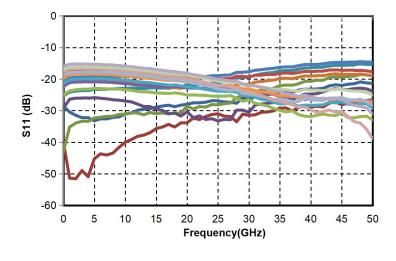
Insertion loss vs. Frequency



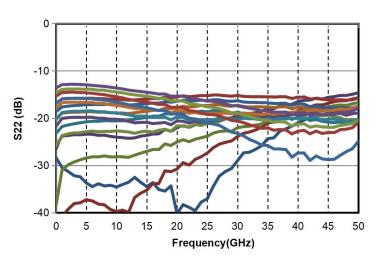
Reference attenuation state vs. Frequency



Input echo vs. Frequency



Output echo vs. Frequency

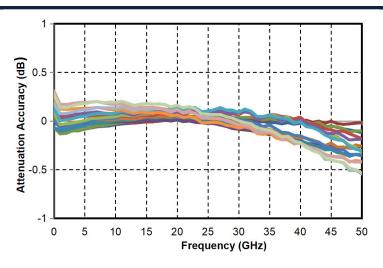


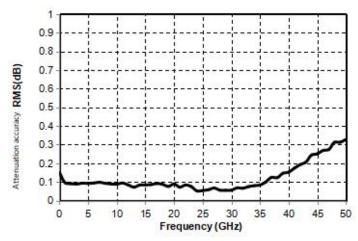
Attenuation accuracy vs. Frequency

Attenuation accuracy RMS vs. Frequency



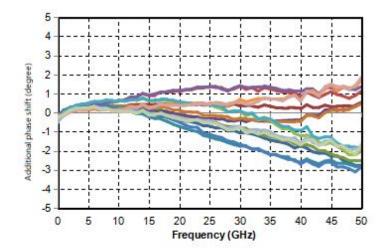
GDA-0050-4B-PD



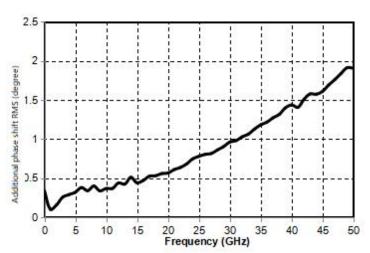


GaAs MMIC Digital Attenuator Chip, DC-50GHz

Additional phase shift vs. Frequency



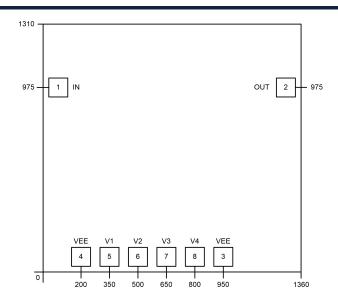
Additional phase shift RMS vs.Frequency



External structure²







[2] The units in the figure are all micrometers. (Boundary dimension tolerance: ± 100 um.)

Definition of bonding pressure point			
Bond point number	Functional	Function Description	
	symbols		
1	RF1	The signal input terminal is externally connected to a 50 ohm circuit, and there is no integrated DC isolation capacitor inside the chip	
2	RF2	The signal output terminal is externally connected to a 50 ohm circuit, and there is no integrated DC isolation capacitor inside the chip	
3、4	VEE	Power supply port	
5~8	VC	Attenuation control pads, refer to the truth table for attenuation control	
Chip bottom	GND	The bottom of the chip needs to have sufficient and good contact with RF and DC ground	

GaAs MMIC Digital Attenuator Chip, DC-50GHz

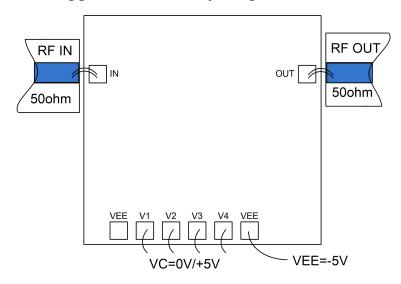
Truth table					
V1	V2	V3	V4	VEE	Conduction pathway
0	0	0	0	-5V	Initial state N=0: attenuation amount is 0
+5V	0	0	0	-5V	Attenuation state N=1: Attenuation amount is 0.25
0	+5V	0	0	-5V	Attenuation state N=2: attenuation amount is 0.5
0	0	+5V	0	-5V	Attenuation state N=4: Attenuation amount is 1
0	0	0	+5V	-5V	Attenuation state N=8: Attenuation amount is 2

Add: 101 cecil street #14-10, tong eng building singapore 069533 Email: info@standardcircuit.com

Web: www.standardcircuit.com Tel: +65 82613258



Suggested assembly diagram



No external resistance is required to control the solder pads.

Precautions for use

- The chip needs to be stored in a container with anti-static function and stored in a nitrogen environment.
- Attempting to clean the surface of bare chips using wet chemical methods is prohibited.
- Please strictly comply with ESD protection requirements to avoid static damage to bare chips.
- Routine operation: Please use precision pointed tweezers to remove the bare chip. During the operation, avoid tools or fingers touching the surface of the chip.
- Suggestion for mounting operation: Bare chip installation can use AuSn solder eutectic sintering or conductive adhesive bonding process. The installation surface must be clean and flat.
- Sintering process: It is recommended to use AuSn solder sheets with a gold tin ratio of 80/20. The working surface temperature reached 255 °C, and the tool (vacuum chuck) temperature reached 265 °C. When a high-temperature mixed gas (nitrogen to hydrogen ratio of 90/10) is blown onto the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip stay above 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive adhesive applied should be as small as possible. After placing
 the chip in the installation position, the conductive adhesive can be vaguely visible around it. Please follow
 the information provided by the conductive adhesive manufacturer for curing conditions.
- Suggestion for bonding operation: Both spherical or wedge-shaped bonding should be used Φ 0.025mm (1mil) gold wire. Thermal ultrasonic bonding temperature is 150 °C. The pressure of the spherical bonding cutter is 40-50GF, and the pressure of the wedge bonding cutter is 18-22GF. Use as little ultrasonic energy as possible. The bonding process starts at the pressing point on the chip and ends at the packaging (or substrate).

Add: 101 cecil street #14-10, tong eng building singapore 069533 Email: info@standardcircuit.com

Web: www.standardcircuit.com Tel: +65 82613258